MDD44-12N1B

Standard Rectifier Module

| V_{RRM} | <i>=</i> 2x 1200 V | | |
|------------------|--------------------|--------|--|
| I _{FAV} | = | 59 A | |
| V _F | = | 1.26 V | |

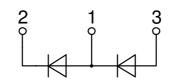
Phase leg

Part number

MDD44-12N1B



Backside: isolated **E**72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- · Very low leakage current

Applications:

- Diode for main rectification
- For single and three phase
- bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- · Field supply for DC motors

Package: TO-240AA

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

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MDD44-12N1B

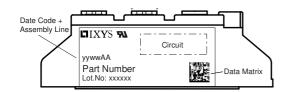
| Rectifier | | | | | Rating | s | |
|--------------------------|-----------------------------------|-----------------------------------|---------------------------------|------|--------|------|------|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| V _{RSM} | max. non-repetitive reverse bloc | king voltage | $T_{VJ} = 25^{\circ}C$ | | | 1300 | V |
| V _{RRM} | max. repetitive reverse blocking | voltage | $T_{VJ} = 25^{\circ}C$ | | | 1200 | V |
| I _R | reverse current | $V_{R} = 1200 V$ | $T_{VJ} = 25^{\circ}C$ | | | 100 | μA |
| | | $V_{R} = 1200 V$ | $T_{vJ} = 150^{\circ}C$ | | | 10 | mA |
| V _F | forward voltage drop | I _F = 100 A | $T_{VJ} = 25^{\circ}C$ | | | 1.30 | V |
| | | I _F = 200 A | | | | 1.60 | V |
| | | $I_{F} = 100 \text{ A}$ | T _{vJ} = 125 °C | | | 1.26 | V |
| | | I _F = 200 A | | | | 1.67 | V |
| FAV | average forward current | T _c = 100°C | $T_{VJ} = 150 ^{\circ}\text{C}$ | | | 59 | А |
| I _{F(RMS)} | RMS forward current | 180° sine | | | | 100 | А |
| V _{F0} | threshold voltage | | $T_{VJ} = 150^{\circ}C$ | | | 0.80 | V |
| r _F | slope resistance } for power | loss calculation only | | | | 4.3 | mΩ |
| R _{thJC} | thermal resistance junction to ca | ase | | | | 0.59 | K/W |
| R _{thCH} | thermal resistance case to heats | sink | | | 0.20 | | K/W |
| P _{tot} | total power dissipation | | $T_c = 25^{\circ}C$ | | | 212 | W |
| I _{FSM} | max. forward surge current | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^{\circ}C$ | | | 1.15 | kA |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 1.24 | kA |
| | | t = 10 ms; (50 Hz), sine | $T_{vJ} = 150^{\circ}C$ | | | 980 | Α |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 1.06 | kA |
| l²t | value for fusing | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^{\circ}C$ | | | 6.62 | kA²s |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 6.40 | kA²s |
| | | t = 10 ms; (50 Hz), sine | $T_{vJ} = 150^{\circ}C$ | | | 4.80 | kA²s |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 4.63 | kA²s |
| C | junction capacitance | V _R = 400 V; f = 1 MHz | $T_{vJ} = 25^{\circ}C$ | | 27 | | pF |

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MDD44-12N1B

| Package | TO-240AA | | | | F | Ratings | S | |
|-----------------------------|---|----------------------|-----------------------------|------|------|---------|------|------|
| Symbol | Definition | Conditions | | | min. | typ. | max. | Unit |
| | RMS current | per terminal | | | | | 200 | Α |
| T _{vj} | virtual junction temperature | | | | -40 | | 150 | °C |
| T _{op} | operation temperature | | | | -40 | | 125 | °C |
| T _{stg} | storage temperature | | | | -40 | | 125 | °C |
| Weight | | | | | | 76 | | g |
| M _D | mounting torque | | | | 2.5 | | 4 | Nm |
| M _T | terminal torque | | | | 2.5 | | 4 | Nm |
| d _{Spp/App} | creepage distance on surface striking distance through ai | terminal to terminal | 13.0 | 9.7 | | | mm | |
| d _{Spb/Apb} | | | terminal to backside | 16.0 | 16.0 | | | mm |
| V | isolation voltage | t = 1 second | | | 3600 | | | V |
| | | t = 1 minute | 50/60 Hz, RMS; liso∟ ≤ 1 mA | | 3000 | | | v |



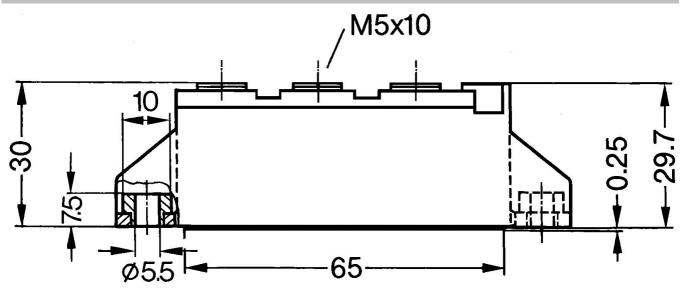
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | MDD44-12N1B | MDD44-12N1B | Box | 36 | 458023 |

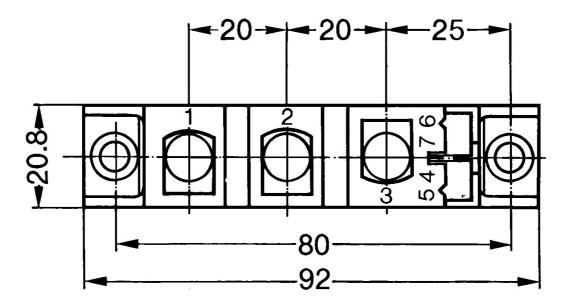
| Similar Part | Package | Voltage class |
|--------------|----------|---------------|
| MDD44-08N1B | TO-240AA | 800 |
| MDD44-14N1B | TO-240AA | 1400 |
| MDD44-16N1B | TO-240AA | 1600 |
| MDD44-18N1B | TO-240AA | 1800 |

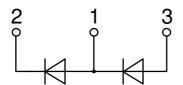
| Equivalent Circuits for Simulation | | | * on die level | $T_{vJ} = 150 \text{ °C}$ |
|------------------------------------|--------------------|-----------|----------------|---------------------------|
| | $-R_{o}$ | Rectifier | | |
| V _{0 max} | threshold voltage | 0.8 | | V |
| $\mathbf{R}_{0 \max}$ | slope resistance * | 3.1 | | mΩ |

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Outlines TO-240AA







DC

60° 30°

100

T_c [°C]

150

200

180° sin 120°

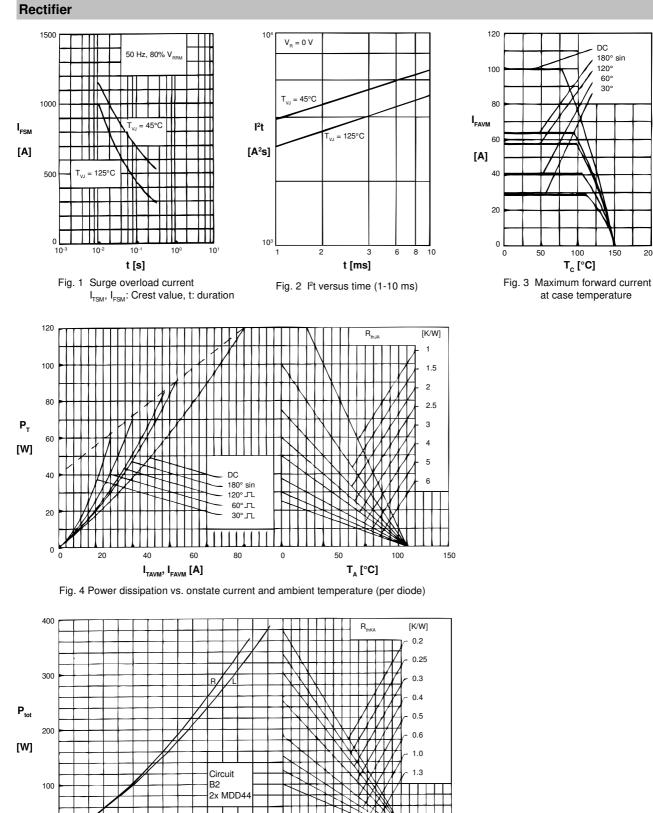


Fig. 6 Single phase rectifier bridge: Power dissipation versus direct output current and ambient temperature; R = resistive load, L = inductive load

0

50

T_▲ [°C]

100

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50

 I_{dAVM} [A]

150

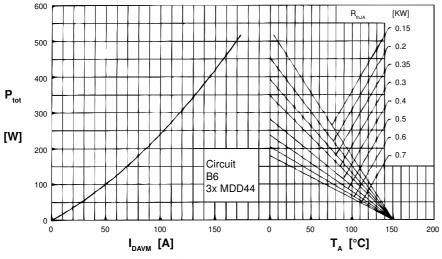
100

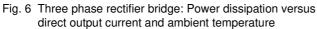
0

0

MDD44-12N1B

Rectifier





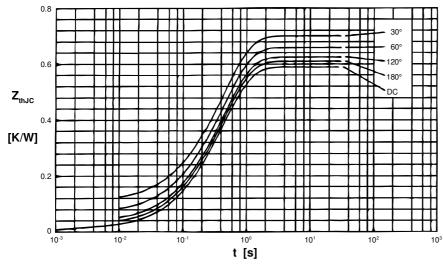
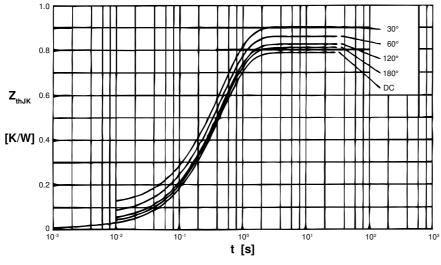


Fig. 7 Transient thermal impedance junction to case (per diode)



| R _{th} | _{JK} for vario | us conduction angles d: | | | |
|-----------------|---|-------------------------|--|--|--|
| | d R _{th} | _{JK} [K/W] | | | |
| | DC | 0.79 | | | |
| | 180° | 0.81 | | | |
| | 120° | 0.83 | | | |
| | 60° | 0.86 | | | |
| | 30° | 0.90 | | | |
| Со | Constants for Z _{th.IK} calculation: | | | | |
| i | R _{thi} [K/W] | t _i [s] | | | |
| 1 | 0.012 | 0.0012 | | | |
| 2 | 0.045 | 0.0950 | | | |
| 3 | 0.533 | 0.4550 | | | |
| 4 | 0.200 | 0.4950 | | | |
| | | | | | |

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 ${\rm R}_{\rm thJC}$ for various conduction angles d:

d R_{thJC} [K/W]

0.59

0.61

0.63

0.66

0.70

Constants for Z_{thJC} calculation:

t_i [s]

0.0012

0.0950

0.4550

DC

180°

120°

60°

30°

i R_{thi} [K/W]

1 2

3

0.012

0.045

0.533

Fig. 8 Transient thermal impedance junction to heatsink (per thyristor)

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